TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC7SZ14F,TC7SZ14FU

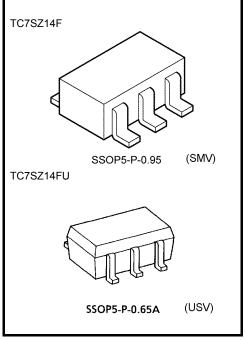
Schmitt Inverter

Features

- High output drive: ±24 mA (min) at V_{CC} = 3 V
- Super high speed operation: t_{pd} = 3.7 ns (typ.)

at $V_{CC} = 5 \text{ V}, 50 \text{ pF}$

- Operation voltage range: V_{CC (opr)} = 1.65~5.5 V
- 5.5-V tolerant inputs
- 5.5-V power down protection output
- Matches the performance of TC74LCX series when operated at 3.3- V V_{CC}



Weight

SSOP5-P-0.95 : 0.016 g (typ.) SSOP5-P-0.65A : 0.006 g (typ.)

Absolute Maximum Ratings (Ta = 25°C)

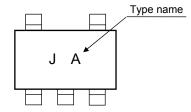
Characteristics	Symbol	Rating	Unit
Supply voltage range	V_{CC}	–0.5 to 6	V
DC input voltage	V _{IN}	−0.5 to 6	V
DC output voltage	V _{OUT}	−0.5 to 6	V
Input diode current	I _{IK}	-20	mA
Output diode current	lok	-20	mA
DC output current	lout	±50	mA
DC V _{CC} /ground current	Icc	±50	mA
Power dissipation	P_{D}	200	mW
Storage temperature	T _{stg}	-65 to 150	°C
Lead temperature (10 s)	TL	260	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating

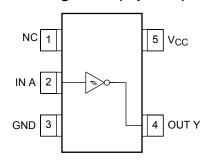
temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Marking



Pin Assignment (top view)



Logic Diagram

Truth Table



Α	Y
L	Н
Н	L

Operating Ranges

Characteristics	Symbol	Rating	Unit
Supply voltage	V	1.65 to 5.5	V
	V _{CC}	1.5 to 5.5 (Note 1)	V
Input voltage	V _{IN}	0 to 5.5	٧
Output voltage	\/a=	0 to 5.5 (Note 2)	V
	Vout	0 to V _{CC} (Note 3)	V
Operating temperature	T _{opr}	-40 to 85	°C

Note 1: Date retention only

Note 2: $V_{CC} = 0 V$

Note 3: High or Low State

Electrical Characteristics

DC Electrical Characteristics

Characteristics		Symbol	Symbol Test Condition			Ta = 25°0		Ta = -4	Unit	
Charac	iciistics	Symbol	rest Condition	V _{CC} (V)	Min	Тур.	Max	Min	Max	Offic
	1			1.65	0.6	1.0	1.4	0.65	1.4	
				1.8	0.7	1.1	1.5	0.7	1.5	
	High lovel	V _P		2.3	1.0	1.4	1.8	1.0	1.8	
High leve	High level	VP	_	3.0	1.3	1.75	2.2	1.3	2.2	
				4.5	1.9	2.45	3.1	1.9	3.1	
Threshold				5.5	2.2	2.9	3.6	2.2	3.6	V
voltage	Low level V _N		_	1.65	0.2	0.5	8.0	0.2	0.8	V
				1.8	0.25	0.55	0.9	0.25	0.9	
		V _N		2.3	0.40	0.75	1.15	0.40	1.15	
				3.0	0.6	1.0	1.5	0.6	1.5	
				4.5	1.0	1.43	2.0	1.0	2.0	
				5.5	1.2	1.70	2.4	1.2	2.4	
				1.65	0.1	0.48	0.9	0.1	1.0	
Hysteresis voltage		age V _H —		1.8	0.15	0.54	1.0	0.15	1.0	V
	14			2.3	0.25	0.65	1.1	0.25	1.1	
	niage		_	3.0	0.4	0.77	1.2	0.4	1.2	
				4.5	0.6	1.01	1.5	0.6	1.5	
				5.5	0.7	1.18	1.7	0.7	1.7	

Characteristics Symbol		Test Condition			Ta = 25°C			Ta = -4	0~85°C	Unit	
Charac	teristics	Symbol	rest	Condition	V _{CC} (V)	Min	Тур.	Max	Min	Max	Offic
			Ic		1.65	1.55	1.65	_	1.55		
					1.8	1.7	1.8	_	1.7		
				I _{OH} = -100 μA	2.3	2.2	2.3	_	2.2	_	
					3.0	2.9	3.0		2.9		
	High level	V _{OH}	$V_{IN} = V_{IL}$		4.5	4.4	4.5		4.4	_	
	riigirievei	VOH	VIN - VIL	I _{OH} = -4 mA	1.65	1.29	1.52		1.29	_	
				I _{OH} = -8 mA	2.3	1.9	2.15		1.9		V
				I _{OH} = -16 mA	3.0	2.4	2.8		2.4		
				I _{OH} = -24 mA	3.0	2.3	2.68		2.3		
Output				$I_{OH} = -32 \text{ mA}$	4.5	3.8	4.2		3.8		
voltage	Low level	V	Mar. Mar.	I _{OL} = 100 μA	1.65	_	0	0.1	_	0.1	
					1.8	_	0	0.1	_	0.1	
					2.3	_	0	0.1	_	0.1	
					3.0	_	0	0.1	_	0.1	
					4.5	_	0	0.1	_	0.1	
	LOW level	V _{OL}	$V_{IN} = V_{IH}$	I _{OL} = 4 mA	1.65	_	0.08	0.24	_	0.24	
		l		I _{OL} = 8 mA	2.3	_	0.1	0.3	_	0.3	
				I _{OL} = 16 mA	3.0	_	0.15	0.4	_	0.4	
				I _{OL} = 24 mA	3.0	_	0.22	0.55	_	0.55	
				I _{OL} = 32 mA	4.5	_	0.22	0.55	_	0.55	
Input leakage	current	I _{IN}	V _{IN} = 5.5 V or GND		0~5.5	_	_	±1	_	±10	μΑ
Power OFF le	eakage	l _{OFF}	V _{IN} or V _{OUT}	= 5.5 V	0.0	_	_	1	_	10	μА
Quiescent su	pply current	Icc	V _{IN} = 5.5 V or GND		1.65~5.5		_	1	_	10	μА

AC Electrical Characteristics (Unless otherwise specified Input: $t_r = t_f = 3$ ns)

Ch avanta vintina	Cumala al	Test Condition		Ta = 25°C			Ta = -4	Unit	
Characteristics	Symbol		V _{CC} (V)	Min	Тур.	Max	Min	Max	Unit
Propagation delay time	t _{pHL}	KL = 1 IVIS2	1.65	2.0	9.1	15.0	2.0	15.6	
			1.8	2.0	7.6	12.5	2.0	13	
			2.5 ± 0.2	1.0	5.0	9.0	1.0	9.5	
			3.3 ± 0.3	1.0	3.7	6.3	1.0	6.5	ns
			5.0 ± 0.5	0.5	3.1	5.2	0.5	5.5	
		C _L = 50 pF,	3.3 ± 0.3	1.5	4.4	7.2	1.5	7.5	
		$R_L = 500 \Omega$	5.0 ± 0.5	0.5	3.7	5.9	0.8	6.2	
Input capacitance	C _{IN}	_	0~5.5	_	4	_	_		pF
Power dissipation capacitance	0	(Note 4)	3.3	_	24	_	_	_	pF
	C _{PD}		5.5	_	30		_	_	pF

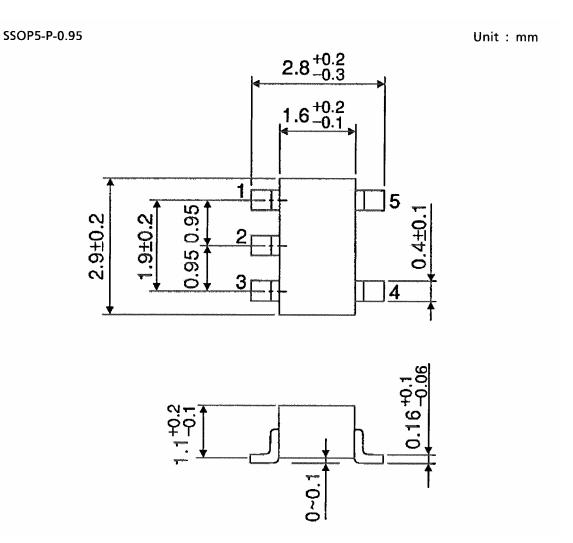
Note 4: CPD is defined as the value of the internal equivalent capacitance which is Calculated from the operating current consumption without load.

Average operating current can be obtained by the equation.

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$

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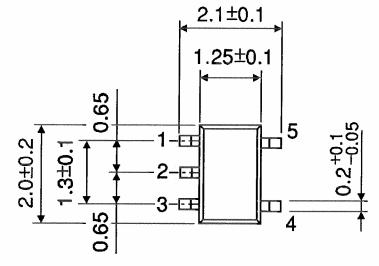
Package Dimensions

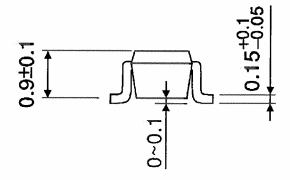


Weight: 0.016 g (typ.)

Package Dimensions

SSOP5-P-0.65A Unit: mm





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Weight: 0.006 g (typ.)

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20070701-EN GENERAL

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